

HD74LVC2G126

Dual Bus Buffer with 3-state Output

REJ03D0212-0200 Rev.2.00 Apr 13, 2006

Description

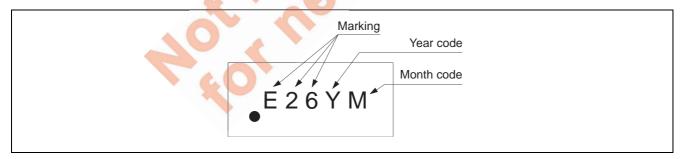
The HD74LVC2G126 has dual bus buffer with 3-state output in an 8-pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as renesas uni logic series.
- Supply voltage range: 1.65 to 5.5 V
- Operating temperature range: -40 to +85°C
- All inputs: V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs: V_0 (Max.) = 5.5 V (@V_{CC} = 0 V)
- Output current: $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$
 - $\pm 8 \text{ mA} (@V_{CC} = 2.3 \text{ V})$
 - $\pm 24 \text{ mA} (@V_{CC} = 3.0 \text{ V}) \\ \pm 32 \text{ mA} (@V_{CC} = 4.5 \text{ V})$
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LVC2G126CLE		SXBG0008KB–A (TBS–8AV)	CL	E (3,000 pcs/reel)

Article Indication





Function Table

Inp		
OE	А	Output Y
Н	Н	Н
Н	L	L
L	Х	Z

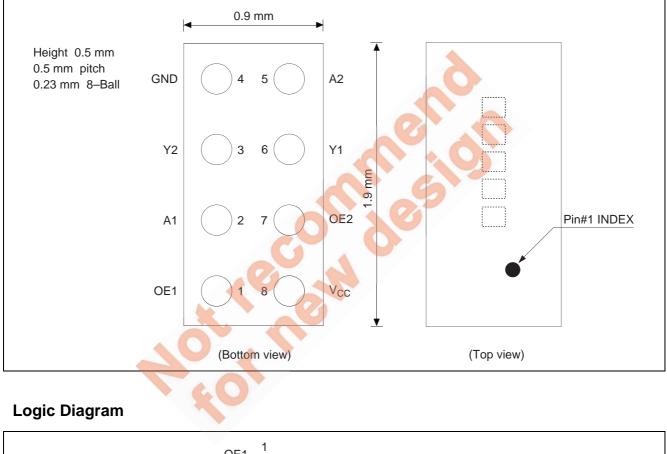
H: High level

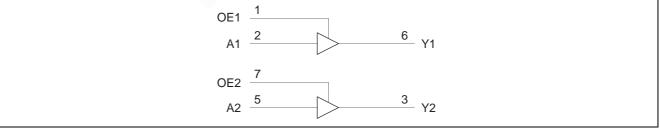
L: Low level

X: Immaterial

Z: High impedance

Pin Arrangement







Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions	
Supply voltage range	V _{CC}	-0.5 to 6.5	V		
Input voltage range ^{*1}	VI	-0.5 to 6.5	V		
Output voltage range *1, 2	Vo	-0.5 to V _{CC} +0.5	V	Output : H or L	
		-0.5 to 6.5		V _{CC} : OFF or Output "Z"	
Input clamp current	I _{IK}	-50	mA	V ₁ < 0	
Output clamp current	I _{ОК}	-50	mA	V ₀ < 0	
Continuous output current	lo	±50	mA	$V_0 = 0$ to V_{CC}	
Continuous current through	I _{CC} or I _{GND}	±100	mA		
V _{CC} or GND					
Package Thermal impedance	θ_{ja}	102	°C/W		
Storage temperature	Tstg	-65 to 150	°C		

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

2. This value is limited to 5.5 V maximum.

Recommended Operating Conditions

Symbol	Min	Max	Unit	Conditions
Vcc	1.65	5.5	V	
VI	0	5.5	V	
Vo	0	Vcc	V	
	0	5.5		Output : Z
IOL		4	mA	V _{CC} = 1.65 V
		8		V _{CC} = 2.3 V
		16		V _{CC} = 3.0 V
		24		
		32		$V_{CC} = 4.5 V$
он		-4		V _{CC} = 1.65 V
	_	-8		V _{CC} = 2.3 V
	_	-16		$V_{CC} = 3.0 V$
	_	-24		
GO I		-32		V _{CC} = 4.5 V
$\Delta t / \Delta v$	0	20	ns / V	V_{CC} = 1.65 to 1.95 V,
				2.3 to 2.7 V
	0	10		V_{CC} = 3.0 to 3.6 V
	0	5		V_{CC} = 4.5 to 5.5 V
Ta	-40	85	°C	
	V _{CC} V ₁ Vo IoL IoL Iон	V _{CC} 1.65 V ₁ 0 V ₀ 0 IoL IOH IOH IOH O IOH O O 0 O 0	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c } V_{CC} & 1.65 & 5.5 & V \\ \hline V_1 & 0 & 5.5 & V \\ \hline V_0 & 0 & V_{CC} & V \\ \hline 0 & 5.5 & V \\ \hline 0 & 5 & V \\ \hline 0 & 10 & V \\ \hline 0 & 5 & V \\ \hline 0 & 10 & V \\ \hline 0 & 5 & V \\ \hline \end{array}$

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

Ta = -40 to $85^{\circ}C$

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test condition
Input voltage	VIH	1.65 to 1.95	V _{CC} ×0.65	_	_	V	
		2.3 to 2.7	1.7	_	_		
		3.0 to 3.6	2.0	_	_		
		4.5 to 5.5	V _{CC} ×0.7	_	_		
	VIL	1.65 to 1.95	_	_	V _{CC} ×0.35		
		2.3 to 2.7			0.7		
		3.0 to 3.6			0.8		
		4.5 to 5.5			V _{CC} ×0.3		
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1		—	V	I _{OH} = –100 µА
		1.65	1.2		—		I _{ОН} =4 mA
		2.3	1.9		—		I _{ОН} = —8 mA
		3.0	2.4		—		I _{OH} = –16 mA
			2.3		—		I _{OH} = –24 mA
		4.5	3.8		—		I _{OH} = –32 mA
	Vol	Min to Max			0.1		I _{OL} = 100 μA
		1.65			0.45		$I_{OL} = 4 \text{ mA}$
		2.3	_	_	0.3		I _{OL} = 8 mA
		3.0	_		0.4		l _{o∟} = 16 mA
				1	0.55		I _{OL} = 24 mA
		4.5	_		0.55		I _{OL} = 32 mA
Input current	l _{in}	0 to 5.5	—		±5	μA	$V_{IN} = 5.5 \text{ V or GND}$
Off state Output current	l _{oz}	3.6			10	μA	$V_0 = 5.5 V \text{ or GND}$
Quiescent supply current	Icc	1.65 to 5.5	5	-	10	μA	$V_{IN} = V_{CC} \text{ or GND},$ $I_0 = 0$
	Δlcc	3 to 5.5	0-	5	500		One input at V _{CC} –0.6 V, Other input at V _{CC} or GND
Output leakage current	I _{OFF}	0	Ā	-	±10	μA	V_{IN} or $V_O = 0$ to 5.5 V
Input capacitance	CIN	3.3		3.5	_	pF	V _{IN} = V _{CC} or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.



Switching Characteristics

 $V_{CC} = 1.8 \pm 0.15 \text{ V}$

		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	3.5	9.8	ns	$C_L = 30 \text{ pF}, R_L = 1.0 \text{ k}\Omega$	A	Y
	t _{PHL}						
Output enable time	t _{ZH}	3.5	10.0	ns		OE	Y
	t _{ZL}						
Output disable time	t _{HZ}	1.7	12.6	ns		OE	Y
	t _{LZ}						

 $V_{CC} = 2.5 \pm 0.2 V$

		Ta = -40 to 85°C				FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.7	4.9	ns	C_L = 30 pF, R_L = 500 Ω	А	Y
	t _{PHL}						
Output enable time	t _{ZH}	1.7	5.0	ns		OE	Y
	t _{ZL}						
Output disable time	t _{HZ}	1.0	5.7	ns		OE	Y
	t _{LZ}						

					0.10	V _{CC}	= 3.3±0.3 V
		Ta = -40) to 85°C	S		FROM	то
Item	Symbol	Min	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.4	4.0	ns	$C_{L} = 50 \text{ pF}, \text{ R}_{L} = 500 \Omega$	А	Y
	t _{PHL}				15		
Output enable time	t _{ZH}	1.5	4.1	ns		OE	Y
	t _{ZL}						
Output disable time	t _{HZ}	1.0	4.4	ns		OE	Y
	t _{LZ}						

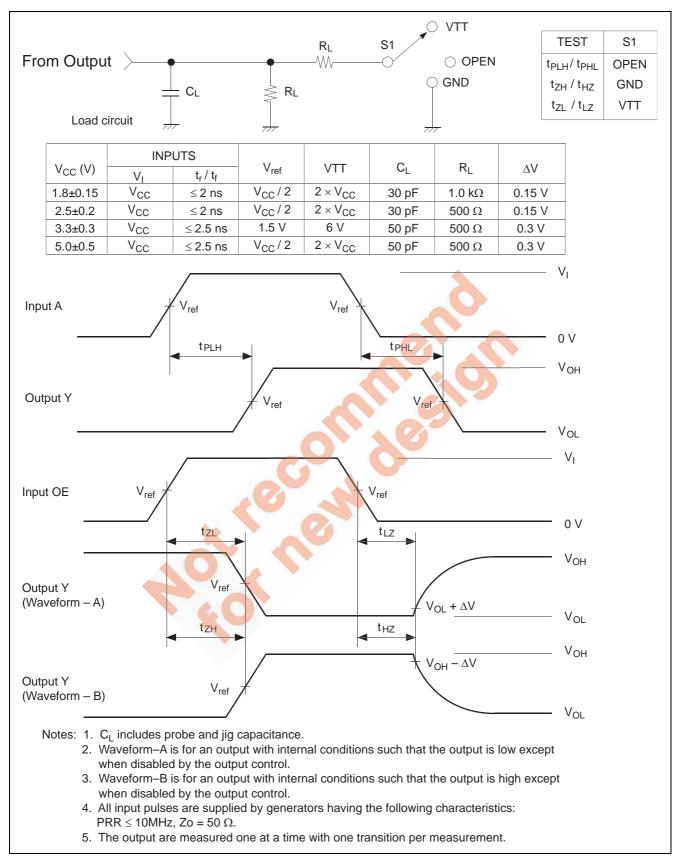
	· La						
			0			V _{CC}	= 5.0±0.5 V
		Ta = -40	to 85°C			FROM	ТО
Item	Symbol	Min 🔪	Max	Unit	Test Conditions	(Input)	(Output)
Propagation delay time	t _{PLH} t _{PHL}	1.0	3.2	ns	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	A	Y
Output enable time	t _{ZH} t _{ZL}	1.0	3.1	ns		OE	Y
Output disable time	t _{HZ} t _{LZ}	1.0	3.3	ns		OE	Y

Operating Characteristics

			Ta = 25°C				
Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation	C _{PD}	1.8	—	19	—	pF	f = 10 MHz
capacitance		2.5	—	19	_		
		3.3	—	20	_		
		5.0	—	22	_		

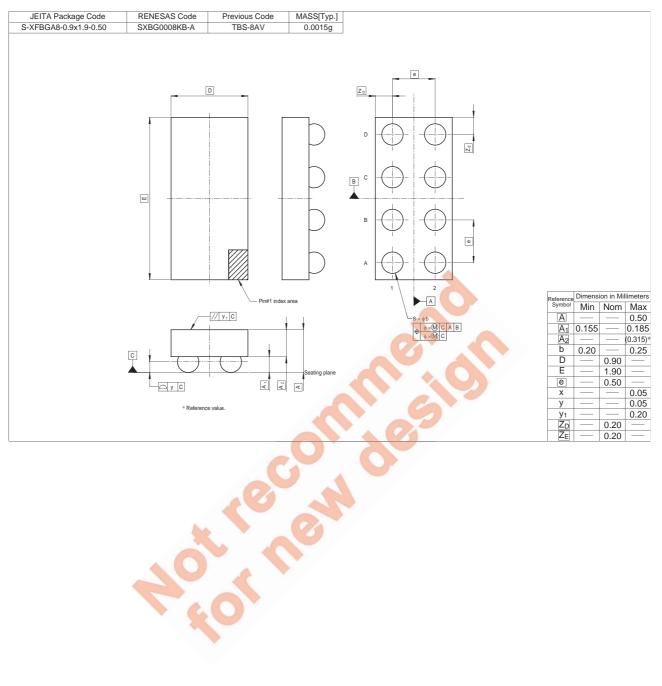


Test Circuit





Package Dimensions





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